

# GBJ25A THRU GBJ25M

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# GBJ25A THRU GBJ25M

## 25.0A Glass Passivated Single Phase Bridge Rectifiers - 50 - 1000V

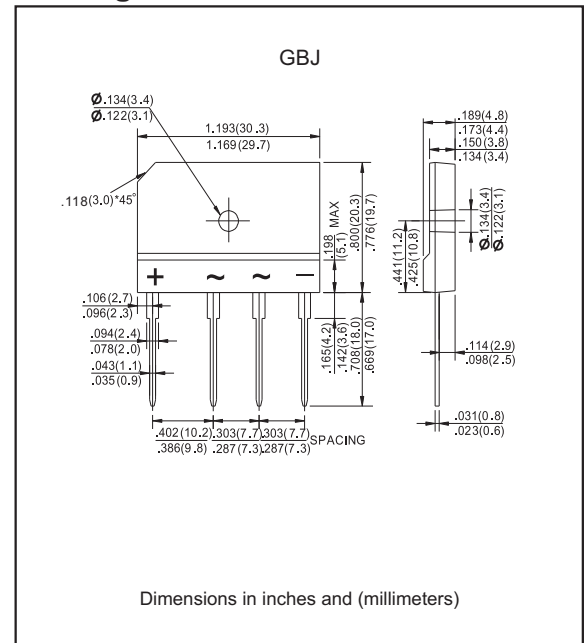
### Features

- Rating to 1000V PRV
- Ideal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junction.
- Lead-free parts meet RoHS requirements.
- UL recognized file # E321971
- Suffix "-H" indicates Halogen free parts, ex. GBJ25A-H.

### Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, GBJ
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : marked on body
- Mounting Position : Any
- Weight : Approximated 7.00 gram

### Package outline



### Maximum ratings and Electrical Characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER                                 | CONDITIONS                                                         | SYMBOL          | MIN. | TYP. | MAX.        | UNIT                 |
|-------------------------------------------|--------------------------------------------------------------------|-----------------|------|------|-------------|----------------------|
| Maximum average forward rectified current | with heatsink Note 1<br>@ $T_c=100^\circ\text{C}$ without heatsink | $I_{F(AV)}$     |      |      | 25.0<br>4.2 | A                    |
| Forward surge current                     | 8.3ms single half sine-wave (JEDEC methode)                        | $I_{FSM}$       |      |      | 350         | A                    |
| Reverse current                           | $V_R = V_{RRM} \quad T_J = 25^\circ\text{C}$                       | $I_R$           |      |      | 10.0        | $\mu\text{A}$        |
|                                           | $V_R = V_{RRM} \quad T_J = 125^\circ\text{C}$                      |                 |      |      | 500         |                      |
| Rating for fusing                         | $t < 8.3 \text{ ms}$                                               | $I^2t$          |      |      | 510         | $\text{A}^2\text{s}$ |
| Typical Junction capacitance Per Element  | Measured at 1.0MHz and applied reverse voltage of 4.0V DC          | $C_J$           |      | 85   |             | pF                   |
| Typical thermal resistance                | Junction to case                                                   | $R_{\theta JC}$ |      | 0.6  |             | $^\circ\text{C/W}$   |
| Storage temperature                       |                                                                    | $T_{STG}$       | -65  |      | +175        | $^\circ\text{C}$     |

Note: 1. Device mounted on 300mm\*300mm\*1.6mm Cu plate heatsink.

| SYMBOLS | $V_{RRM}^{*1}$<br>(V) | $V_{RMS}^{*2}$<br>(V) | $V_R^{*3}$<br>(V) | $V_F^{*4}$<br>(V) | Operating temperature<br>$T_J, (^\circ\text{C})$ |
|---------|-----------------------|-----------------------|-------------------|-------------------|--------------------------------------------------|
| GBJ25A  | 50                    | 35                    | 50                | 1.10              | -55 to +150                                      |
| GBJ25B  | 100                   | 70                    | 100               |                   |                                                  |
| GBJ25D  | 200                   | 140                   | 200               |                   |                                                  |
| GBJ25G  | 400                   | 280                   | 400               |                   |                                                  |
| GBJ25J  | 600                   | 420                   | 600               |                   |                                                  |
| GBJ25K  | 800                   | 560                   | 800               |                   |                                                  |
| GBJ25M  | 1000                  | 700                   | 1000              |                   |                                                  |

\*1 Repetitive peak reverse voltage

\*2 RMS voltage

\*3 Continuous reverse voltage

\*4 Maximum forward voltage@ $I_F=12.5\text{A}$

## Rating and characteristic curves (GBJ25A THRU GBJ25M)

FIG.1-FORWARD CURRENT DERATING CURVE

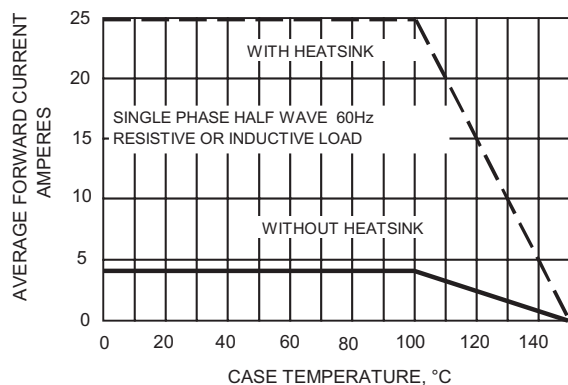


FIG.2-MAXMUN NON-REPETITIVE  
SURGE CURRENT

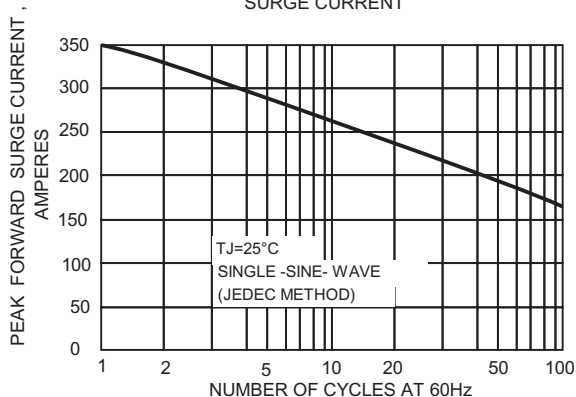


FIG.3-TYPICAL JUNCTION CAPACITANCE

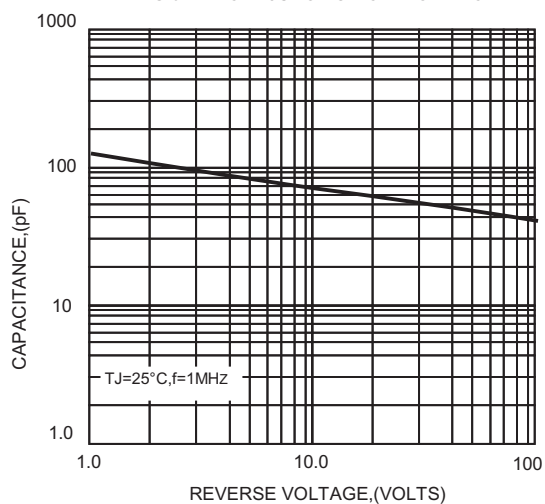


FIG.4-TYPICAL FORWARD CHARACTERISTICS

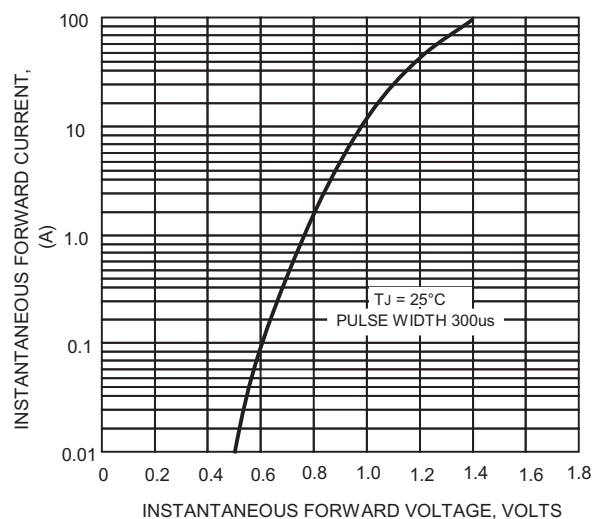
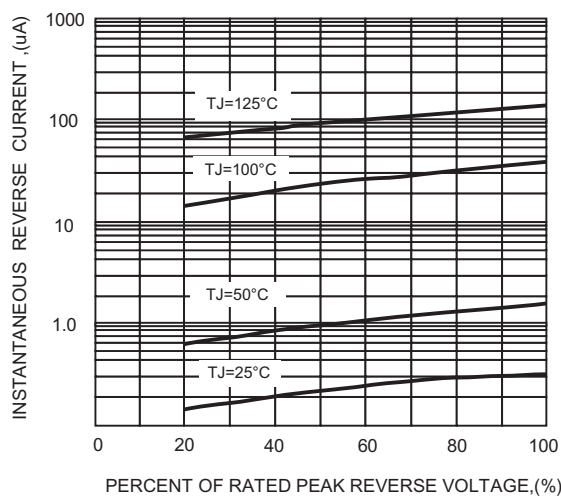
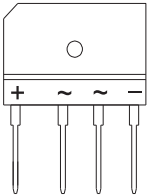
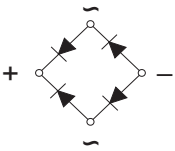


FIG.5-TYPICAL REVERSE CHARACTERISTICS



# GBJ25A THRU GBJ25M

## Pinning information

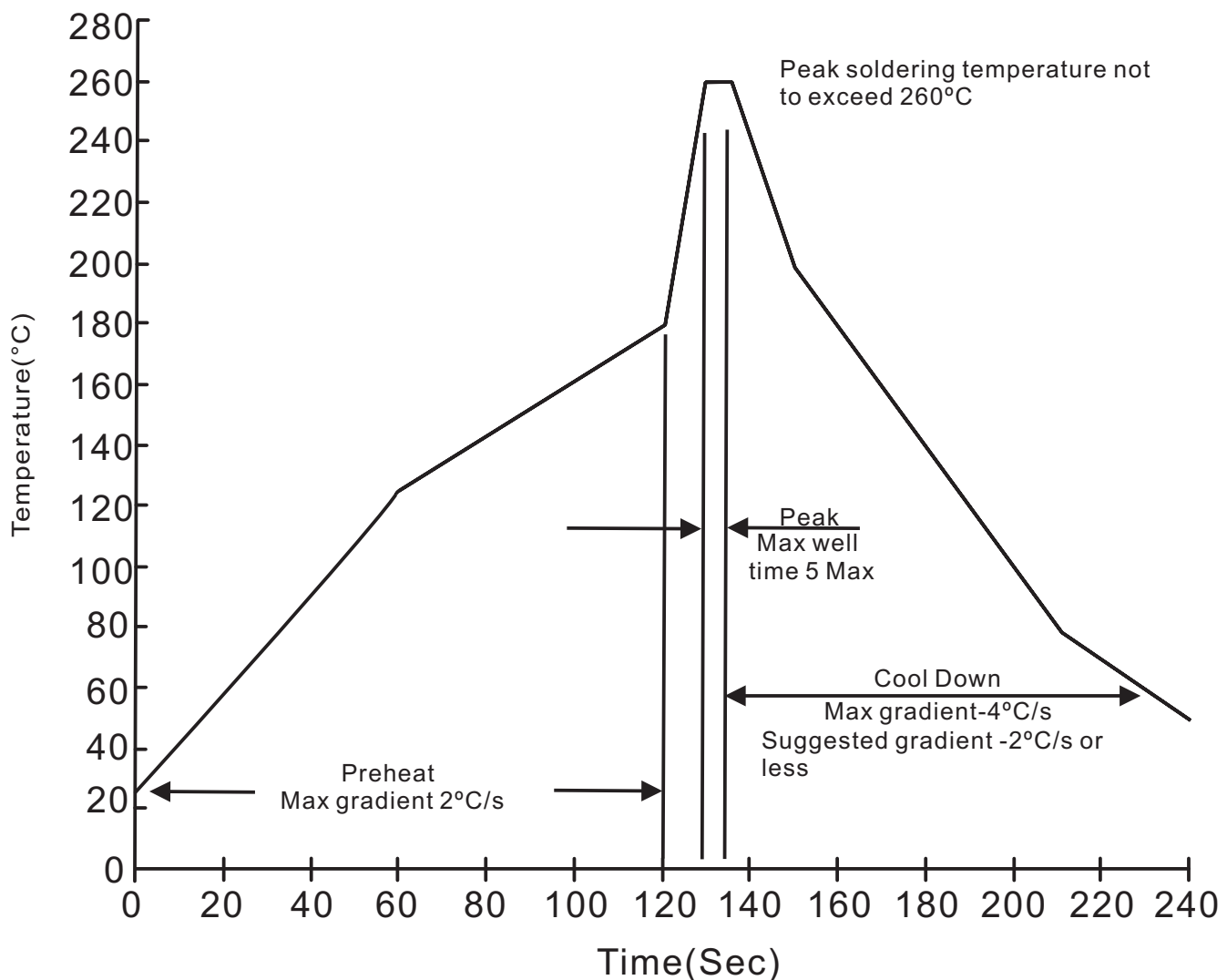
| Simplified outline                                                                | Symbol                                                                            |
|-----------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|
|  |  |

## Marking

| Type number | Marking code |
|-------------|--------------|
| GBJ25A      | GBJ25A       |
| GBJ25B      | GBJ25B       |
| GBJ25D      | GBJ25D       |
| GBJ25G      | GBJ25G       |
| GBJ25J      | GBJ25J       |
| GBJ25K      | GBJ25K       |
| GBJ25M      | GBJ25M       |

## Tube packing

| PACKAGE | TUBE<br>(pcs) | TUBE SIZE<br>(m/m) | CARTON<br>SIZE<br>(m/m) | CARTON<br>(pcs) | APPROX.<br>GROSS WEIGHT<br>(kg) |
|---------|---------------|--------------------|-------------------------|-----------------|---------------------------------|
| GBJ     | 15            | 475*42.0*8.1       | 496*224*101             | 750             | 7.8                             |

**GBJ25A THRU GBJ25M****Suggested thermal profiles for soldering processes****1. Lead free temperature profile wave-soldering**

# GBJ25A THRU GBJ25M

## High reliability test capabilities

| Item Test                         | Conditions                                                                                                                                 | Reference                     |
|-----------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|
| 1. Solder Resistance              | at $260 \pm 5^{\circ}\text{C}$ for $10 \pm 2$ sec.<br>immerse body into solder $1/16" \pm 1/32"$                                           | MIL-STD-750D<br>METHOD-2031   |
| 2. Solderability                  | at $245 \pm 5^{\circ}\text{C}$ for 5 sec.                                                                                                  | MIL-STD-202F<br>METHOD-208    |
| 3. High Temperature Reverse Bias  | $V_R = 80\%$ rate at $T_J = 150^{\circ}\text{C}$ for 168 hrs.                                                                              | MIL-STD-750D<br>METHOD-1038   |
| 4. Forward Operation Life         | Rated average rectifier current at $T_A = 25^{\circ}\text{C}$ for 500hrs.                                                                  | MIL-STD-750D<br>METHOD-1027   |
| 5. Intermittent Operation Life    | $T_A = 25^{\circ}\text{C}$ , $I_F = I_O$<br>On state: power on for 5 min.<br>off state: power off for 5 min.<br>on and off for 500 cycles. | MIL-STD-750D<br>METHOD-1036   |
| 6. Pressure Cooker                | $15P_{SIG}$ at $T_A = 121^{\circ}\text{C}$ for 4 hrs.                                                                                      | JESD22-A102                   |
| 7. Temperature Cycling            | $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ dwelled for 30 min.<br>and transferred for 5min. total 10 cycles.                          | MIL-STD-750D<br>METHOD-1051   |
| 8. Forward Surge                  | 8.3ms single half sine-wave , one surge.                                                                                                   | MIL-STD-750D<br>METHOD-4066-2 |
| 9. Humidity                       | at $T_A = 85^{\circ}\text{C}$ , RH=85% for 1000hrs.                                                                                        | MIL-STD-750D<br>METHOD-1021   |
| 10. High Temperature Storage Life | at $175^{\circ}\text{C}$ for 1000 hrs.                                                                                                     | MIL-STD-750D<br>METHOD-1031   |